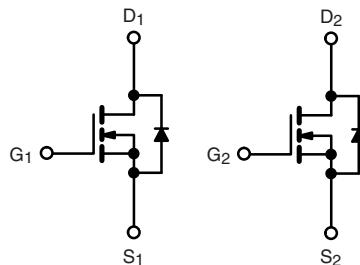
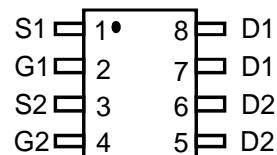


PRODUCT SUMMARY

- $V_{DS} (V) = 60V$
- $I_D = 7A$ ($V_{GS}=10V$)
- $R_{DS(ON)} < 40m\Omega$ ($V_{GS} = 10V$)
- $R_{DS(ON)} < 55m\Omega$ ($V_{GS} = 4.5V$)



N-Channel MOSFET N-Channel MOSFET



SOP-8

ABSOLUTE MAXIMUM RATINGS ($T_C = 25^\circ C$, unless otherwise noted)

| PARAMETER | | SYMBOL | LIMIT | UNIT |
|---|----------------------|----------------|-------------|------|
| Drain-Source Voltage | | V_{DS} | 60 | V |
| Gate-Source Voltage | | V_{GS} | ± 20 | |
| Continuous Drain Current | $T_C = 25^\circ C$ | I_D | 7 | A |
| | $T_C = 125^\circ C$ | | 4 | |
| Continuous Source Current (Diode Conduction) ^a | | I_S | 3.6 | |
| Pulsed Drain Current ^b | | I_{DM} | 28 | |
| Single Pulse Avalanche Current | $L = 0.1 \text{ mH}$ | I_{AS} | 18 | mJ |
| Single Pulse Avalanche Energy | | E_{AS} | 16.2 | |
| Maximum Power Dissipation ^b | $T_C = 25^\circ C$ | P_D | 4 | W |
| | $T_C = 125^\circ C$ | | 1.3 | |
| Operating Junction and Storage Temperature Range | | T_J, T_{stg} | -55 to +175 | °C |

THERMAL RESISTANCE RATINGS

| PARAMETER | | SYMBOL | LIMIT | UNIT |
|--------------------------|------------------------|------------|-------|------|
| Junction-to-Ambient | PCB Mount ^c | R_{thJA} | 110 | °C/W |
| Junction-to-Foot (Drain) | | R_{thJF} | 34 | |

Notes

- Package limited.
- Pulse test; pulse width $\leq 300 \mu\text{s}$, duty cycle $\leq 2\%$.
- When mounted on 1" square PCB (FR4 material).

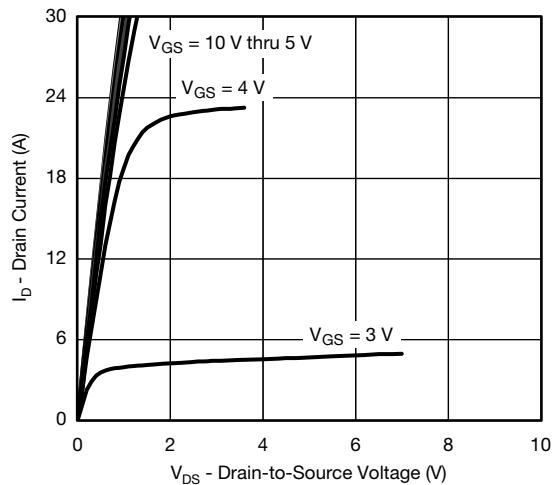
SPECIFICATIONS ($T_C = 25^\circ\text{C}$, unless otherwise noted)

| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN. | TYP. | MAX. | UNIT | |
|--|---------------------|---|---|------|------|-----------|------------------|--|
| Static | | | | | | | | |
| Drain-Source Breakdown Voltage | V_{DS} | $V_{GS} = 0 \text{ V}$, $I_D = 250 \mu\text{A}$ | | 60 | - | - | V | |
| Gate-Source Threshold Voltage | $V_{GS(\text{th})}$ | $V_{DS} = V_{GS}$, $I_D = 250 \mu\text{A}$ | | 1.5 | 2.0 | 2.5 | | |
| Gate-Source Leakage | I_{GSS} | $V_{DS} = 0 \text{ V}$, $V_{GS} = \pm 20 \text{ V}$ | | - | - | ± 100 | nA | |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{GS} = 0 \text{ V}$ | $V_{DS} = 60 \text{ V}$ | - | - | 1 | μA | |
| | | $V_{GS} = 0 \text{ V}$ | $V_{DS} = 60 \text{ V}$, $T_J = 125^\circ\text{C}$ | - | - | 50 | | |
| | | $V_{GS} = 0 \text{ V}$ | $V_{DS} = 60 \text{ V}$, $T_J = 175^\circ\text{C}$ | - | - | 150 | | |
| On-State Drain Current ^a | $I_{D(\text{on})}$ | $V_{GS} = 10 \text{ V}$ | $V_{DS} \geq 5 \text{ V}$ | 20 | - | - | A | |
| Drain-Source On-State Resistance ^a | $R_{DS(\text{on})}$ | $V_{GS} = 10 \text{ V}$ | $I_D = 4.5 \text{ A}$ - | | 28 | 40 | $\text{m}\Omega$ | |
| | | $V_{GS} = 4.5 \text{ V}$ | $I_D = 4 \text{ A}$ - | | 30 | 55 | | |
| Forward Transconductance ^f | g_{fs} | $V_{DS} = 15 \text{ V}$, $I_D = 4.5 \text{ A}$ | | - | 15 | - | S | |
| Dynamic ^b | | | | | | | | |
| Input Capacitance | C_{iss} | $V_{GS} = 0 \text{ V}$ | $V_{DS} = 25 \text{ V}$, $f = 1 \text{ MHz}$ | - | 600 | 750 | pF | |
| Output Capacitance | C_{oss} | | | - | 110 | 140 | | |
| Reverse Transfer Capacitance | C_{rss} | | | - | 50 | 62 | | |
| Total Gate Charge ^c | Q_g | $V_{GS} = 10 \text{ V}$ | $V_{DS} = 30 \text{ V}$, $I_D = 5.3 \text{ A}$ | - | 11.7 | 18 | nC | |
| Gate-Source Charge ^c | Q_{gs} | | | - | 1.8 | 2.7 | | |
| Gate-Drain Charge ^c | Q_{gd} | | | - | 2.8 | 4.2 | | |
| Gate Resistance | R_g | $f = 1 \text{ MHz}$ | | 1.3 | - | 6 | Ω | |
| Turn-On Delay Time ^c | $t_{d(\text{on})}$ | $V_{DD} = 30 \text{ V}$, $R_L = 6.8 \Omega$ $I_D \approx 4.4 \text{ A}$, $V_{GEN} = 10 \text{ V}$, $R_g = 1 \Omega$ | | - | 7 | 11 | ns | |
| Rise Time ^c | t_r | | | - | 3.3 | 5 | | |
| Turn-Off Delay Time ^c | $t_{d(\text{off})}$ | | | - | 22.4 | 33.5 | | |
| Fall Time ^c | t_f | | | - | 2.1 | 3.2 | | |
| Source-Drain Diode Ratings and Characteristics ^b | | | | | | | | |
| Pulsed Current ^a | I_{SM} | | | - | - | 28 | A | |
| Forward Voltage | V_{SD} | $I_F = 2 \text{ A}$, $V_{GS} = 0 \text{ V}$ | | - | 0.75 | 1.1 | V | |

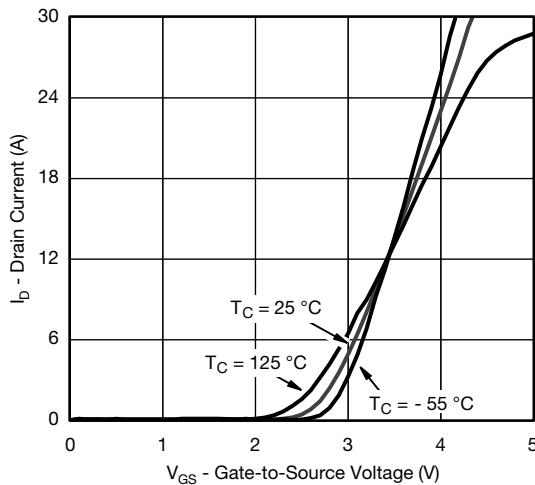
Notes

- Pulse test; pulse width $\leq 300 \mu\text{s}$, duty cycle $\leq 2 \%$.
- Guaranteed by design, not subject to production testing.
- Independent of operating temperature.

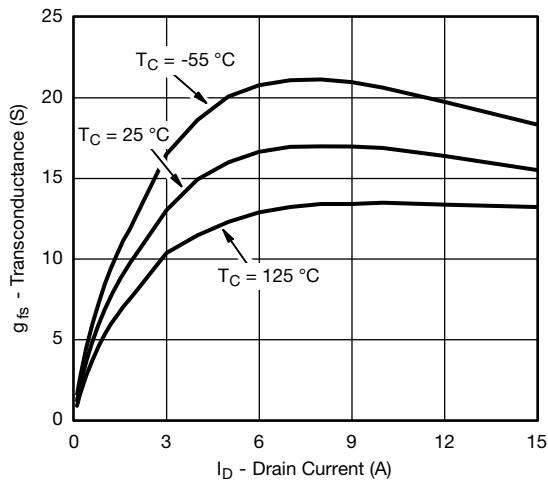
TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise noted)



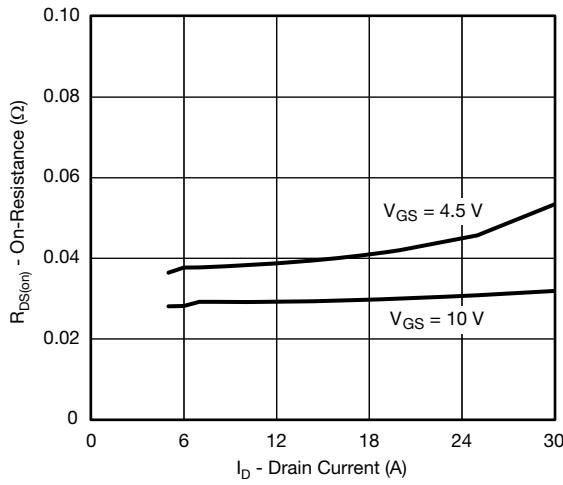
Output Characteristics



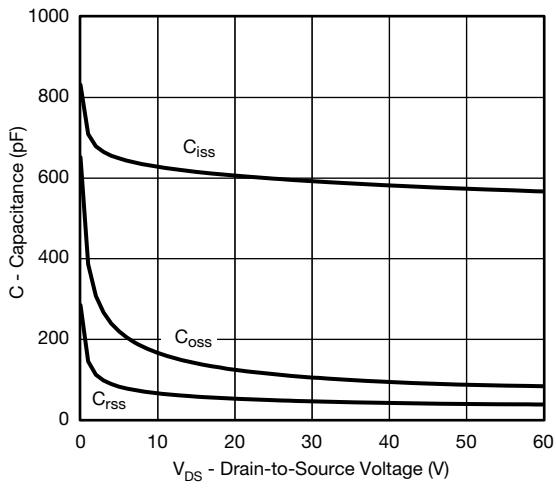
Transfer Characteristics



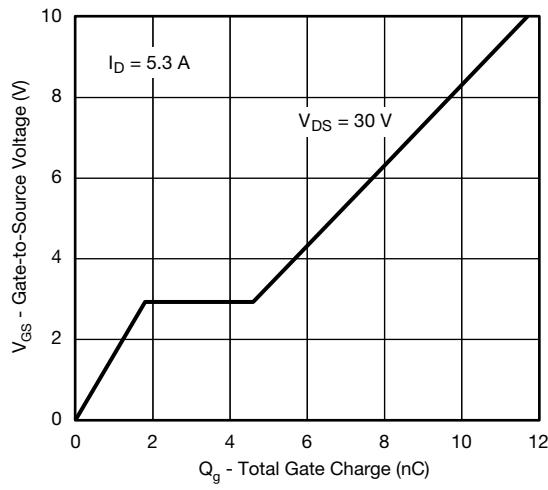
Transconductance



On-Resistance vs. Drain Current

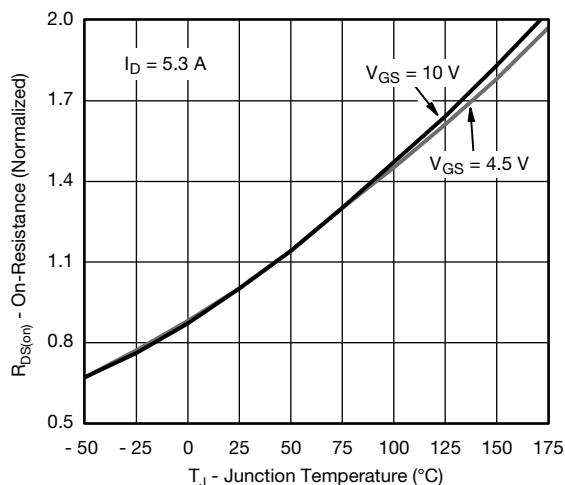


Capacitance

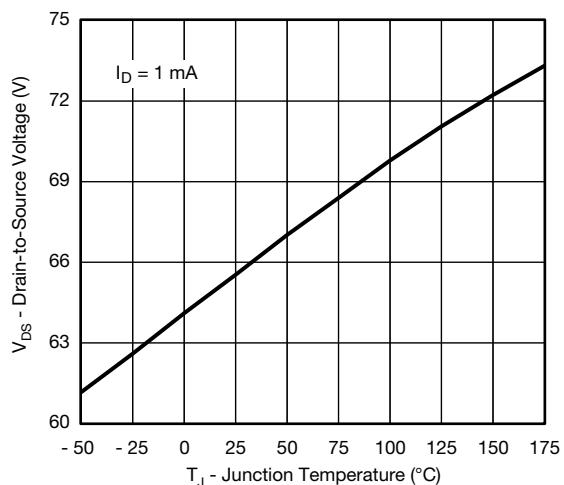


Gate Charge

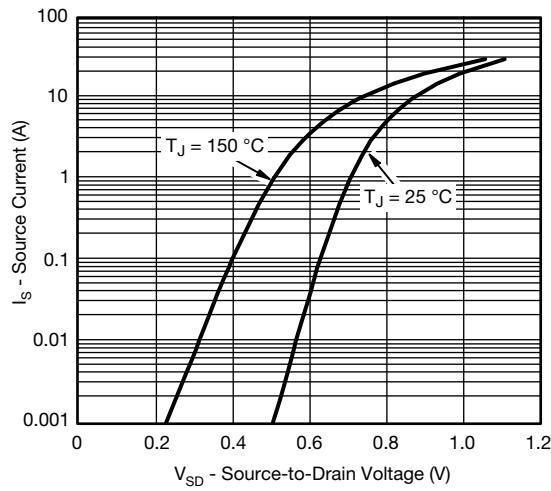
TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise noted)



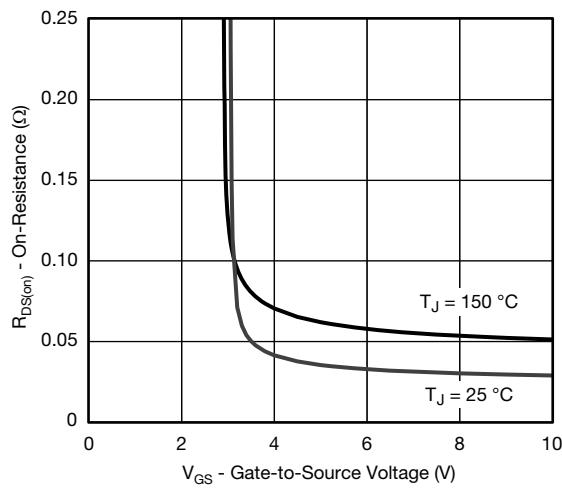
On-Resistance vs. Junction Temperature



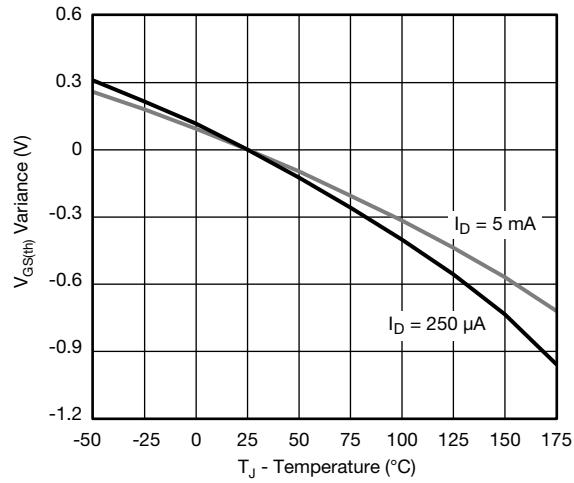
Drain Source Breakdown vs. Junction Temperature



Source Drain Diode Forward Voltage

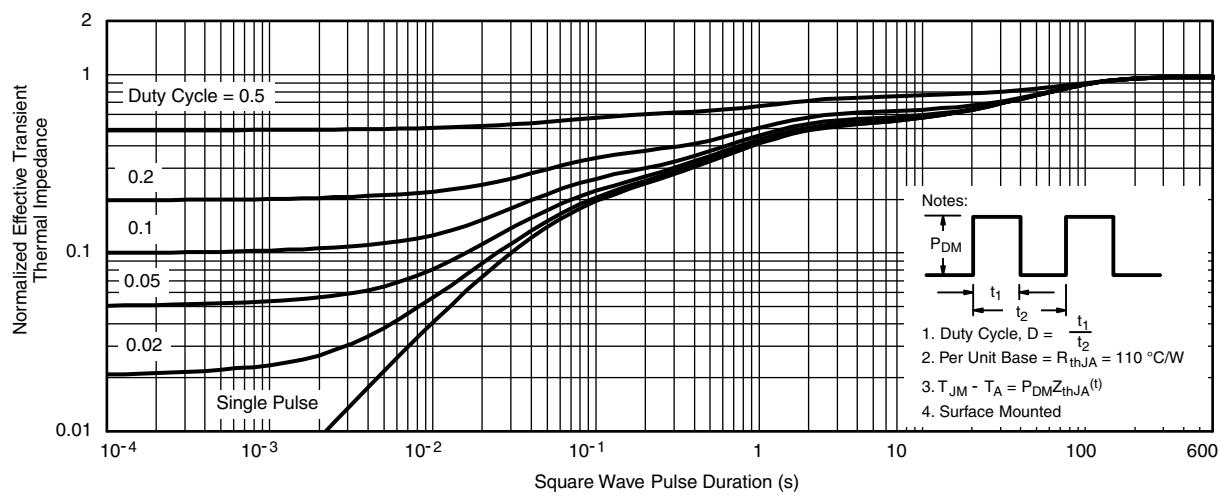
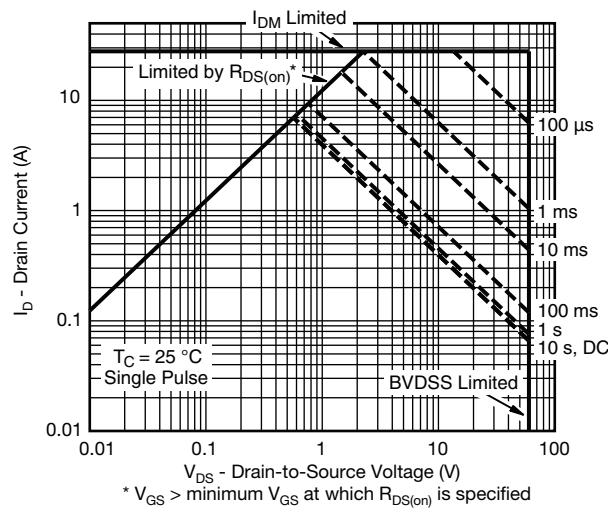


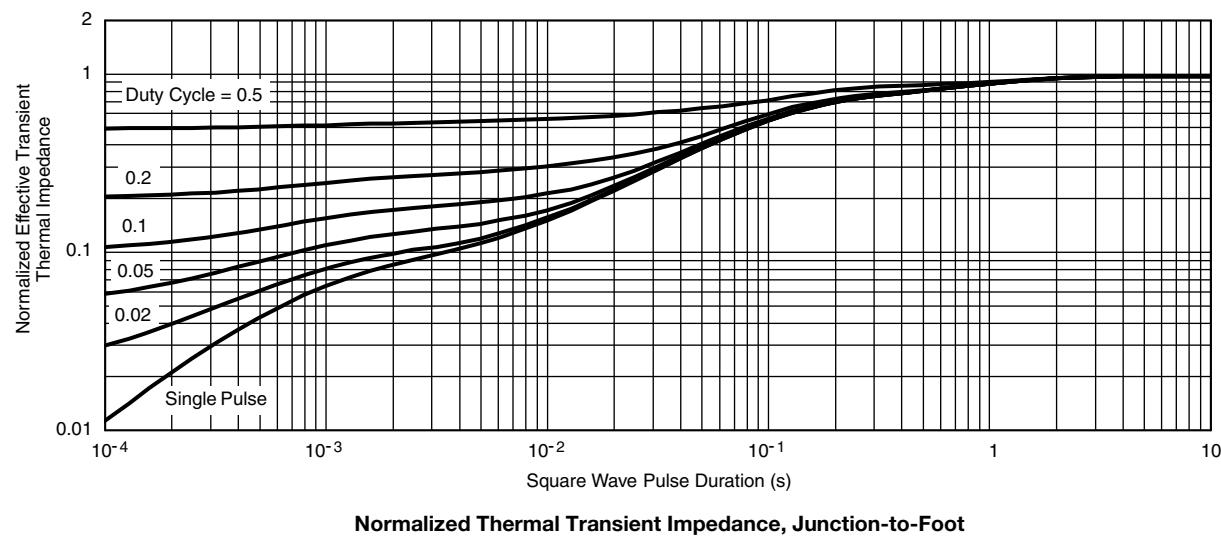
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage

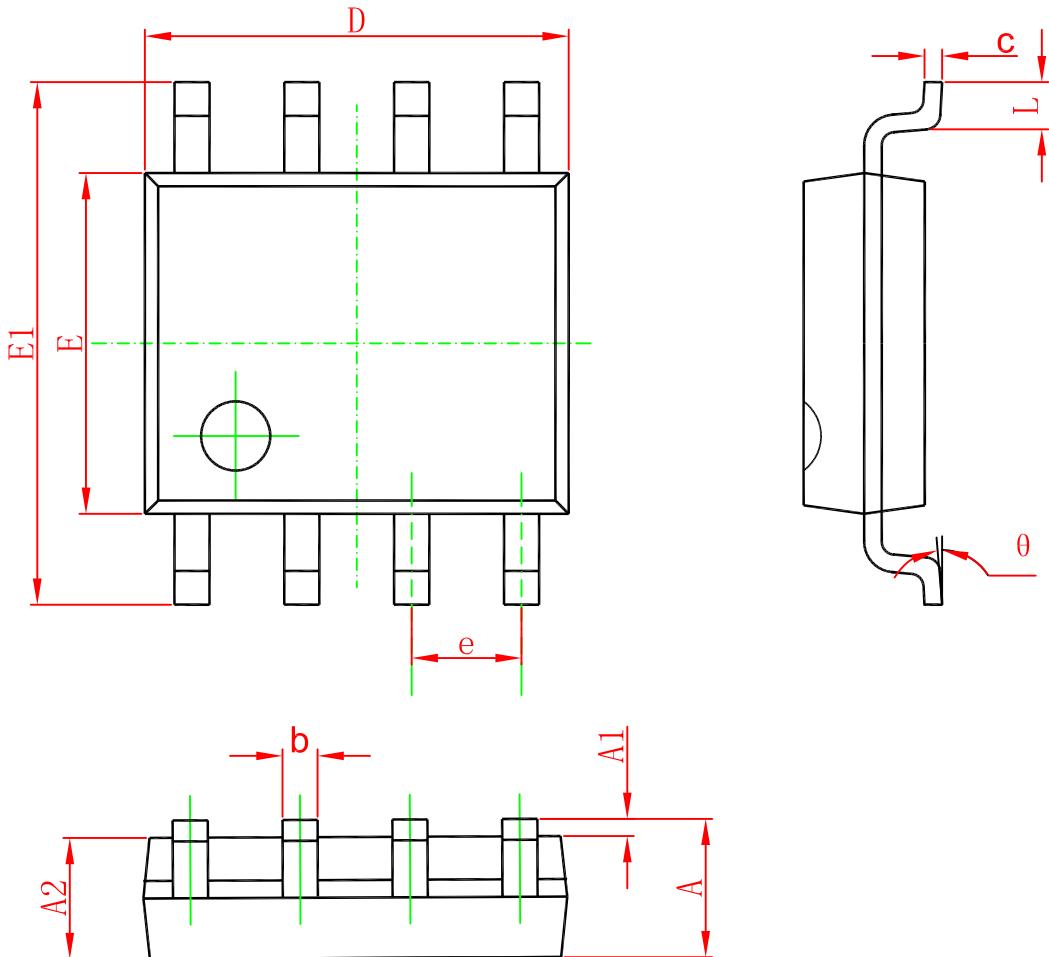
THERMAL RATINGS ($T_A = 25^\circ\text{C}$, unless otherwise noted)



THERMAL RATINGS ($T_A = 25^\circ\text{C}$, unless otherwise noted)

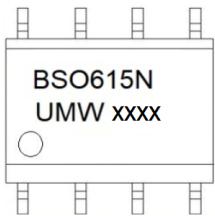
Normalized Thermal Transient Impedance, Junction-to-Foot

SOP-8



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|-------|----------------------|-------|
| | Min | Max | Min | Max |
| A | 1.350 | 1.750 | 0.053 | 0.069 |
| A1 | 0.100 | 0.250 | 0.004 | 0.010 |
| A2 | 1.350 | 1.550 | 0.053 | 0.061 |
| b | 0.330 | 0.510 | 0.013 | 0.020 |
| c | 0.170 | 0.250 | 0.006 | 0.010 |
| D | 4.700 | 5.100 | 0.185 | 0.200 |
| E | 3.800 | 4.000 | 0.150 | 0.157 |
| E1 | 5.800 | 6.200 | 0.228 | 0.244 |
| e | 1.270(BSC) | | 0.050(BSC) | |
| L | 0.400 | 1.270 | 0.016 | 0.050 |
| θ | 0° | 8° | 0° | 8° |

Marking



| Order code | Package | Baseqty | Deliverymode |
|--------------|---------|---------|---------------|
| UMW BSO615NG | SOP-8 | 3000 | Tape and reel |

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